

>>> mathematical description of reactive sputtering in c  
>>> based on berg model described in Journal of Vacuum  
Science & Technology A: Vacuum, Surfaces, and Films 5, 202  
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equation A5 for flux  $F$  of nitrogen molecules:

$$F = \frac{p_N}{\sqrt{2k_B\pi TM}} \quad (1)$$

equation A1' for target fractional coverage  $\theta_1$ :

$$2\alpha_t F(1 - \theta_1) - \frac{J}{e} S_N \theta_1 = 0 \quad (2)$$

equation A2' for chamber wall and substrate fractional coverage  $\theta_2$ :

$$2\alpha_c F(1 - \theta_2) + \frac{J}{e} S_N \theta_1 \frac{A_t}{A_c} (1 - \theta_2) - \frac{J}{e} S_M (1 - \theta_1) \frac{A_t}{A_c} \theta_2 = 0 \quad (3)$$

equation A3 for flow to target:

$$q_t = \alpha_t F(1 - \theta_1) A_t \quad (4)$$

>>> steady state equations

equation A4 for flow to surface area  $A_c$  of the chamber:

$$q_c = \alpha_c F(1 - \theta_2) A_c \quad (5)$$

equation 2 for flow through pump:

$$q_p = p_N S \quad (6)$$

equation 1 for incoming reactive gas flow:

$$q_0 = q_t + q_c + q_p \quad (7)$$

equation A6 for total sputtering rate  $Y$ :

$$Y = \frac{J}{e} [S_N \theta_1 + S_M (1 - \theta_1)] \quad (8)$$

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>>> algorithm
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solve the equations by assuming a value for  $p_N$ . equations are already solved except A1' and A2', they can be written as:

$$\theta_1 = \frac{1}{1 + \frac{JS_N}{2e\alpha_t F}} \quad (9)$$

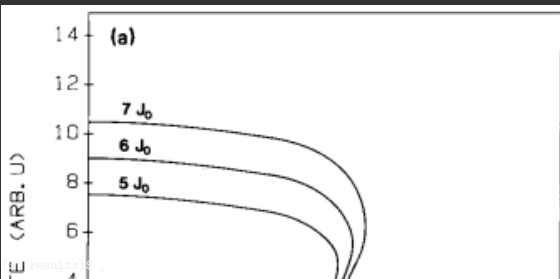
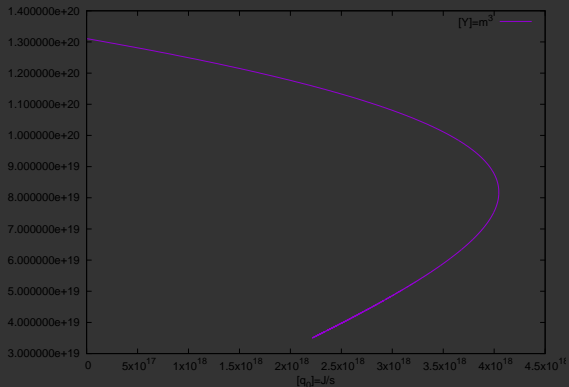
$$\theta_2 = \frac{\frac{e}{J}2\alpha_c F \frac{A_c}{A_t} + S_N \theta_1}{\frac{e}{J}2\alpha_c F \frac{A_c}{A_t} + S_N \theta_1 + S_M(1 - \theta_1)} \quad (10)$$

now assume a new (little higher) value for  $p_N$

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>>> results
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for  $n=5000$  iterations,  $dp = 10^{-6}\text{Pa}$  pressure change,  $p_N = 10^{-7}\text{Pa}$  initial nitrogen partial pressure,  $T=300\text{Kelvin}$ ,  $M = 4.651 \cdot 10^{-26}\text{kg}$  mass of nitrogen molecule,  $S_N = 0.3$  sputtering yield of compound by incoming argon ions,  $J = 14 \frac{\text{A}}{\text{m}^2}$  current density of argon ions causing sputtering from target surface,  $A_t = 0.127\text{m}^2$  target surface,  $A_c = 1.27\text{m}^2$  exposed chamber surface,  $S_M = 1.5$  sputtering yield of elemental metal material by incoming argon ions,  $S = 85 \frac{\text{l}}{\text{s}}$  pumping speed,  $\alpha_t = 1$  sticking coefficient for nitrogen molecule to titanium target and  $\alpha_c = 1$  sticking coefficient for nitrogen molecule to titanium covered part  $(1 - \theta_2)$  of chamber wall you can get these relationships: although for  $Y$  the lower part seems to be missing and for  $P_N$  the higher part seems to be missing

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>>> results
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>>> results
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